

SWITCHING P-CHANNEL POWER MOS FET

DESCRIPTION

NEC

The 2SJ601 is P-channel MOS Field Effect Transistor designed for solenoid, motor and lamp driver.

FEATURES

• Low on-state resistance: $R_{DS(on)1} = 31 \text{ m}\Omega \text{ MAX.} (V_{GS} = -10 \text{ V}, \text{ ID} = -18 \text{ A})$

 $R_{DS(on)2}$ = 46 m Ω MAX. (V_{GS} = -4.0 V, I_D = -18 A)

- Low input capacitance:
 C_{iss} = 3300 pF TYP. (V_{DS} = -10 V, V_{GS} = 0 V)
- Built-in gate protection diode
- TO-251/TO-252 package

ABSOLUTE MAXIMUM RATINGS (TA = 25°C)

Drain to Source Voltage (VGs = 0 V)	VDSS	-60	V
Gate to Source Voltage (VDS = 0 V)	Vgss	∓20	V
Drain Current (DC) (Tc = 25°C)	D(DC)	∓36	А
Drain Current (pulse) ^{Note1}	D(pulse)	∓120	А
Total Power Dissipation (Tc = 25°C)	Рт	65	W
Total Power Dissipation (T _A = 25°C)	Рт	1.0	W
Channel Temperature	Tch	150	°C
Storage Temperature	Tstg	–55 to +150	°C
Single Avalanche Current Note2	las	-35	А
Single Avalanche Energy Note2	Eas	123	mJ

★ ORDERING INFORMATION

PART NUMBER	PACKAGE		
2SJ601	TO-251 (MP-3)		
2SJ601-Z	TO-252 (MP-3Z)		

(TO-251)



(TO-252)



Notes 1. PW \leq 10 μ s, Duty Cycle \leq 1%

2. Starting T_{ch} = 25°C, V_{DD} = -30 V, R_G = 25 Ω , V_{GS} = $-20 \rightarrow 0$ V

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The mark \star shows major revised points.

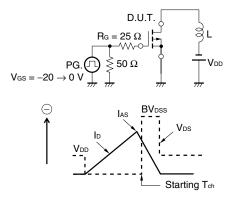
ELECTRICAL CHARACTERISTICS (TA = 25°C)

CHARACTERISTICS	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNIT
Zero Gate Voltage Drain Current	IDSS	V _{DS} = -60 V, V _{GS} = 0 V			-10	μA
Gate Leakage Current	lgss	V _{GS} = ∓20 V, V _{DS} = 0 V			∓10	μA
Gate Cut-off Voltage	V _{GS(off)}	V _{DS} = -10 V, I _D = -1 mA	-1.5	-2.0	-2.5	V
Forward Transfer Admittance Note	y _{fs}	V _{DS} = -10 V, I _D = -18 A	15	30		S
Drain to Source On-state Resistance Note	RDS(on)1	V _{GS} = −10 V, I _D = −18 A		25	31	mΩ
	RDS(on)2	V _{GS} = -4.0 V, I _D = -18 A		32	46	mΩ
Input Capacitance	Ciss	V _{DS} = -10 V		3300		pF
Output Capacitance	Coss	V _{GS} = 0 V		580		pF
Reverse Transfer Capacitance	Crss	f = 1 MHz		230		pF
Turn-on Delay Time	td(on)	I _D = -18 A		11		ns
Rise Time	tr	V _{GS} = -10 V		12		ns
Turn-off Delay Time	td(off)	V _{DD} = -30 V		80		ns
Fall Time	tr	R _G = 0 Ω		53		ns
Total Gate Charge	QG	V _{DD} = -48 V		63		nC
Gate to Source Charge	QGS	V _{GS} = -10 V		10		nC
Gate to Drain Charge	Qgd	I⊳ = –36 A		16		nC
Body Diode Forward Voltage Note	VF(S-D)	I⊧ = 36 A, V _{GS} = 0 V		1.0		V
Reverse Recovery Time	trr	IF = 36 A, V _{GS} = 0 V		52		ns
Reverse Recovery Charge	Qrr	di/dt = 100 A/ <i>µ</i> s		108		nC

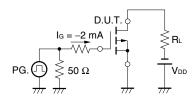
* Note Pulsed

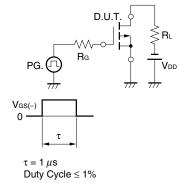
TEST CIRCUIT 1 AVALANCHE CAPABILITY

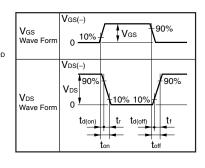
TEST CIRCUIT 2 SWITCHING TIME



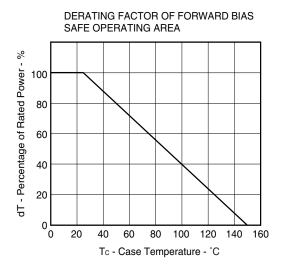
TEST CIRCUIT 3 GATE CHARGE

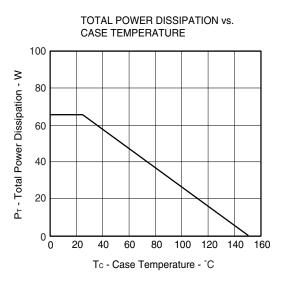




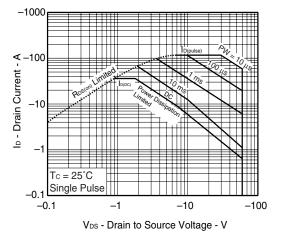


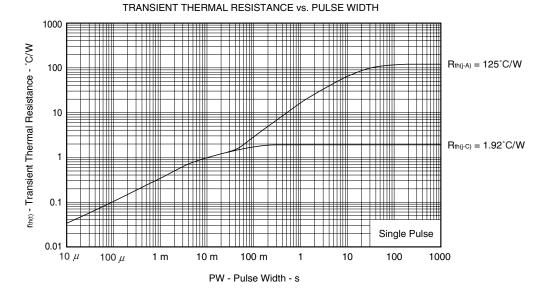
TYPICAL CHARACTERISTICS ($T_A = 25^{\circ}C$)

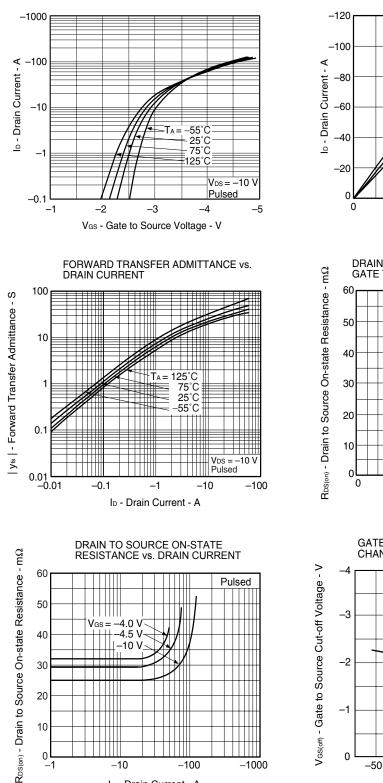




FORWARD BIAS SAFE OPERATING AREA





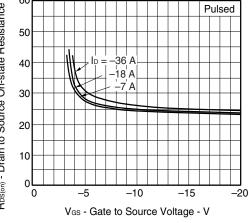


FORWARD TRANSFER CHARACTERISTICS

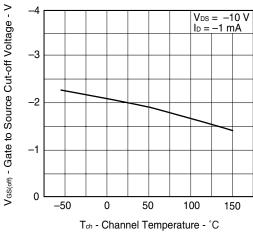
DRAIN TO SOURCE VOLTAGE Vgs= -10 V 4.5 V -4.0 V Pulsed -2 -1 -3 -4 -5 VDS - Drain to Source Voltage - V

DRAIN CURRENT vs.

DRAIN TO SOURCE ON-STATE RESISTANCE vs. GATE TO SOURCE VOLTAGE







10

0

-1

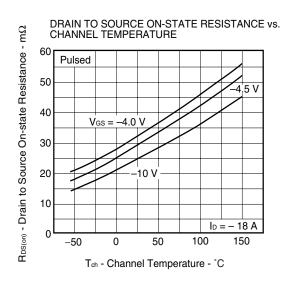
-10

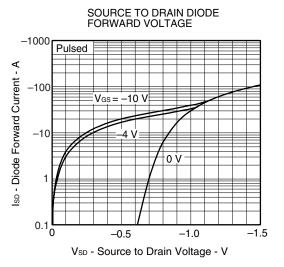
ID - Drain Current - A

-100

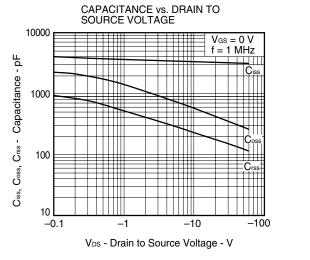
-1000

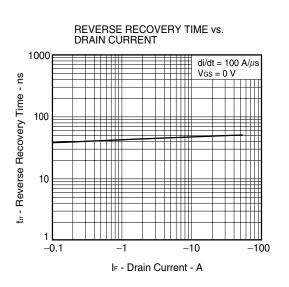


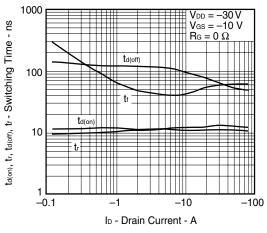


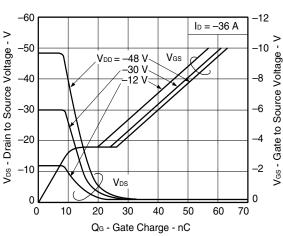


SWITCHING CHARACTERISTICS

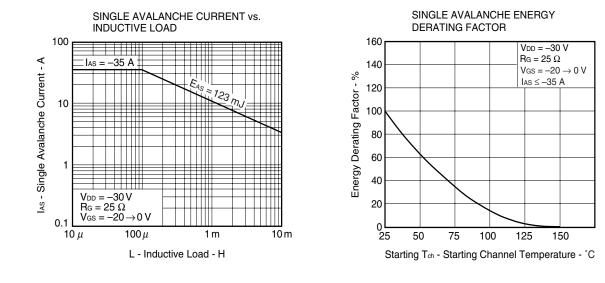




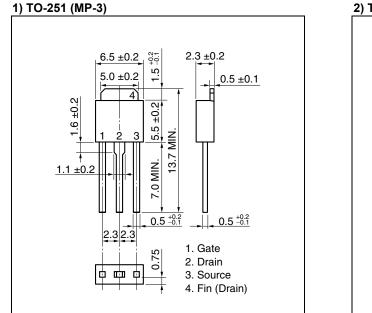


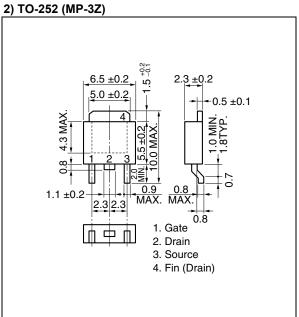


DYNAMIC INPUT/OUTPUT CHARACTERISTICS

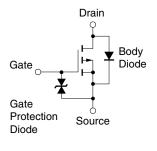


★ PACKAGE DRAWINGS (Unit: mm)





EQUIVALENT CIRCUIT



Remark The diode connected between the gate and source of the transistor serves as a protector against ESD. When this device actually used, an additional protection circuit is externally required if a voltage exceeding the rated voltage may be applied to this device.

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